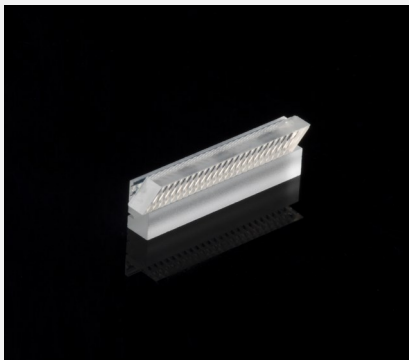


# Beam Transformation System

## BTS(FAC160)-P0.2



### Features and Advantages

Beam Transformation System (BTS) for diode laser bars with up to 50 emitters: emitter size up to 100  $\mu\text{m}$ , emitter pitch 200  $\mu\text{m}$ . The BTS is used to make the beam parameter product of diode laser bars symmetrical for free beam lasers or fiber coupling.

The BTS consists of a FAC160 fast axis collimation lens, a lens array for 90° rotation of the emitters and a bottom tab.

### Product Specifications

Specification Data	Unit	Value
Material		FL-IR1.9 / S-TIH53 (Ohara)
Length (L)	mm	12 $\pm$ 0.1
Width (W)	mm	0.8 $\pm$ 0.1
Clear aperture	mm <sup>2</sup>	10.5 x 0.25
Surface quality @ 633 nm		$\lambda/4$ (typically)
Back focal length BFL @ 980 nm	mm	0.034
Pitch	mm	0.2
Gap	mm	0.0 $\pm$ 0.01
Numerical aperture (NA)		FA: 0.5 SA: 0.09
Transmission	%	> 98
Remaining divergence (FW1/e <sup>2</sup> ) for fast axis <sup>(1)</sup>	mrad	< 12

Product Code	MOD000674 <sup>(2)</sup>	MOD000681 <sup>(2)</sup>	MOD000682	MOD000722 <sup>(2)</sup>
<b>Specification Data</b>	<b>Unit</b>	<b>Value</b>		
AR-coating	nm	600 - 700	790 - 990	790 - 990
Thickness (T)	mm	1.5 $\pm$ 0.1	1.5 $\pm$ 0.1	1.5 $\pm$ 0.1
Divergence measured at	nm	808		
Divergence optimized for	nm		808	976
Drawing Number		a	a	a

<sup>(1)</sup> Depending on laser parameters / specification is valid for an emitter-height of 1  $\mu\text{m}$  and no smile of the laser diode.

<sup>(2)</sup> Example for customization.

### Product Dimensions (mm)

